

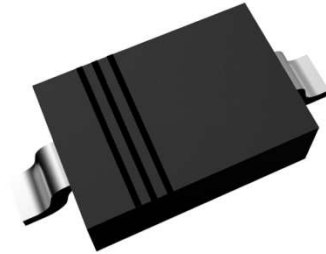
SK VARIABLE CAPACITANCE DIODE SILICON TYPE

Application

- Frequency modulation in FM Radio
- FM and AFC in communication set

Features

- Excellent linearity
- Capacitance ratio: $C_{0.5V}/C_{5.0V}=3.25$ (Typ)
- Low series resistance: $r_s \leq 0.8\Omega$
- package: SOD-323



SOD-323

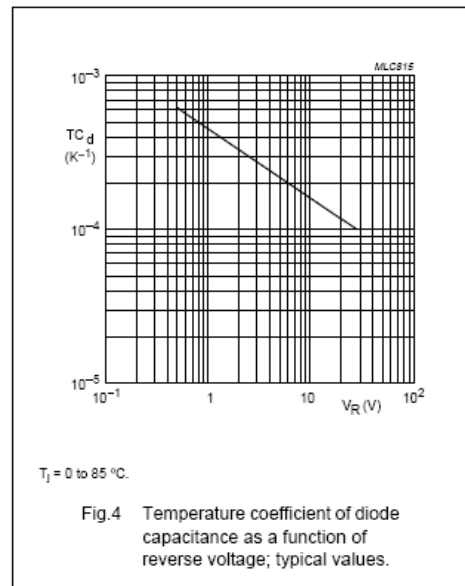
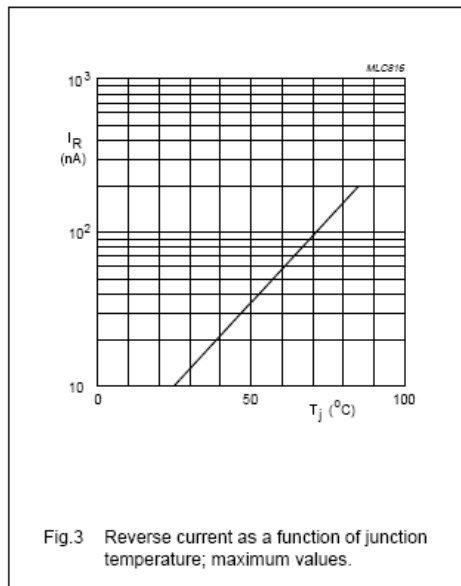
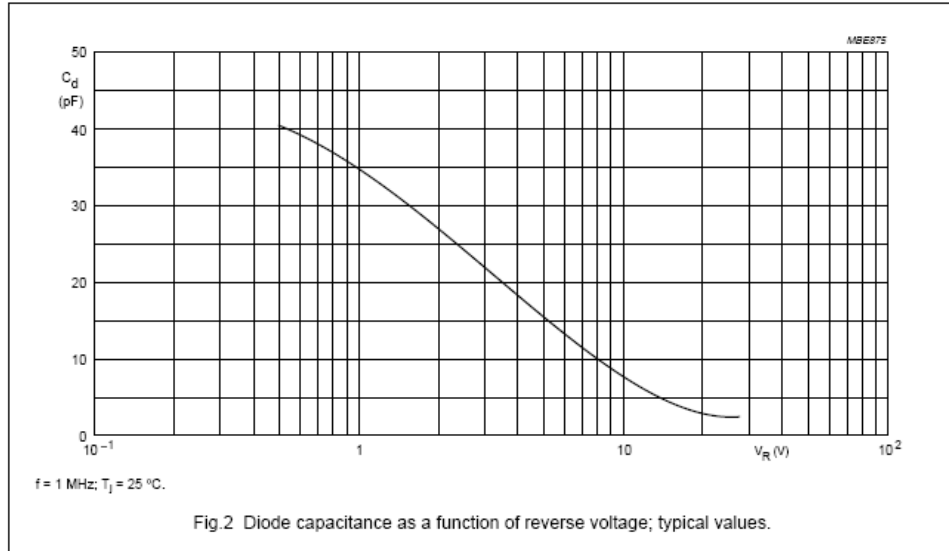
Maximum ratings

Parameter	Symbol	Rating		Unit
		Min	Max	
Assignment Temperature Range	T_{amb}	-55	100	°C
Storage Temperature Range	T_{atg}	-55	125	°C
Maximum Reverse voltage	V_{RM}		6	V
Junction Temperature	T_j		125	°C
Forward voltage($I_F=20mA$)	V_F		1	V

Electrical Characteristics(at $T_{amb}=25^\circ C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Diode capacitance	C1	$VR1=0.5V$	35	40	45	PF
Diode capacitance	C2	$VR2=5V$	10		20	PF
Capacitance ratio	C1/C2	$VR1=0.5V, VR2=5V$	1.2		5	
Reverse Current	IR	$VR=6V$			10	nA
Forward Voltage	VF	$IF=20mA$			1	V
series resistance	r_s	$F=470MHz, C0=14pF$			0.8	Ω

GRAPHICAL DATA



单击下面可查看定价，库存，交付和生命周期等信息

[>>SHIKUES\(时科\)](#)